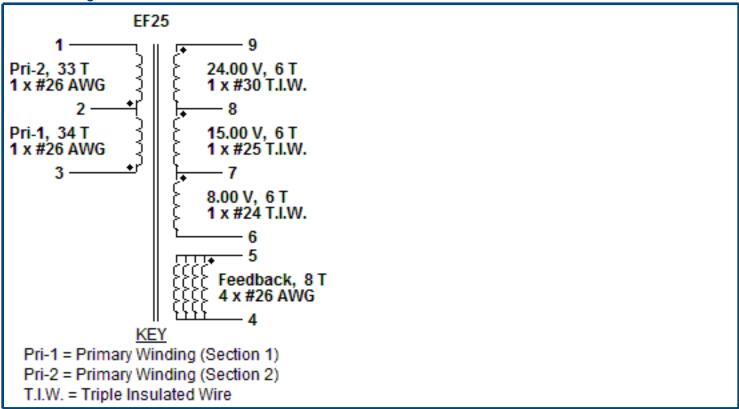
INPUT	INFO	ОИТРИТ	UNIT	ACDC_LinkSwitchHP_060623 Rev 2-2.xls: LinkSwitch-HP Flyback Continuous/Discontinuous Transformer Design Spreadsheet
				Customer
67		67	V	Minimum AC Input Voltage
215		215	V	Maximum AC Input Voltage
		50	Hz	AC Mains Frequency
24.00		24.00	V	Output Voltage (main)
15.00		15.00	W	Load Power
		0.80		Efficiency Estimate
		0.50		Loss Allocation Factor
		10.00	V	Bias Voltage
		3.00	ms	Bridge Rectifier Conduction Time Estimate
		45	иF	Input Filter Capacitor
E/V		E/V		E and V Package Selected
				Open Frame type enclosure
		Frame		Specific Spe
Metal		Metal		Metallic heatsink thermally connected to the exposed metal on the E-package
1 NK6762E		1 NK6762E		Manual Device Selection
LINKO703E			1	Minimum Current limit
+				
+				Maximum current limit
				External Minimum Current limit
1.			A	External Maximum current limit
1		_		Current limit reduction factor
				Program delay Resistor
			nF	Program delay Capacitor
<u> </u>			sec	Total program delay
1		132	kHz	LinkSwitch-HP Switching Frequency
		120	kHz	LinkSwitch-HP Minimum Switching Frequency
		136	kHz	LinkSwitch-HP Maximum Switching Frequency
0.60		0.60		Ripple to Peak Current Ratio (0.4 < KP < 6.0)
90.00		90.00	V	Reflected Output Voltage
		88.00	V	Undervoltage turn on
		36.67	V	Undervoltage turn off
		390.18	V	Overvoltage threshold
		132.47	kHz	Maximum switching frequency at full load
		116.89	kHz	Minimum switching frequency at full load
		3.39	us	Minimum available Diode conduction time at full load. This should be greater than 2.5 us
		1.77	us	Minimum available Diode conduction time at light load. This should be greater than 1.4 us
		3.00	V	LinkSwitch-HP on-state Drain to Source Voltage.
		0.50	V	Output Winding Diode Forward Voltage Drop
		0.70	V	Bias Winding Diode Forward Voltage Drop
	67 215 24.00 15.00 E/V Open Frame Metal LNK6763E	67 215 24.00 15.00 E/V Open Frame Metal LNK6763E 1	67 67 67 215 215 50 24.00 24.00 15.00 15.00 0.80 0.50 10.00 3.00 45 E/V E/V Open Frame Open Frame Metal Metal LNK6763E LNK6763E 0.716 0.824 0.716 0.824 1 1 1 1 1 1 124.00 33.0 0.86 132 120 136 0.60 90.00 90.00 88.00 36.67 390.18 132.47 116.89 3.39 1.77	67 67 V 215 V 50 Hz 24.00 V 15.00 15.00 W 0.80 0.50 10.00 V 3.00 ms 45 UF E/V E/V Open Frame Metal Metal LNK6763E LNK6763E 0.716 A 0.824 A 0.716 A 0.824 A 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1

FEEDBACK SENSING SECTION					
RFB1			40.20	k-ohms	Feedback divider upper resistor
RFB2			9.09	k-ohms	Feedback divider lowerr resistor
ENTER TRANSFORMER CORE/CONSTRUCTION VARIABLES					
Select Core Size	EF25		EF25		Manual Core Selected
Core			EF25		Selected Core
Custom Core					Enter name of custom core is applicable
AE			0.52	cm^2	Core Effective Cross Sectional Area
LE			5.78	ст	Core Effective Path Length
AL			2000	nH/T^2	Ungapped Core Effective Inductance
BW			15.60	mm	Bobbin Physical Winding Width
М			0.00	mm	Safety Margin Width (Half the Primary to Secondary Creepage Distance)
L	2		2		Number of Primary Layers
NS	18		18		Number of Secondary Turns
DC INPUT VOLTAGE PARAMETERS					
VMIN	80		80	V	Minimum DC Input Voltage
VMAX	300		300	V	Maximum DC Input Voltage
CURRENT WAVEFORM SHAPE PARAMETERS					
DMAX			0.54		Maximum Duty Cycle
IAVG			0.23	Α	Average Primary Current
IP			0.62	Α	Peak Primary Current
IR			0.37	Α	Primary Ripple Current
IRMS			0.33	А	Primary RMS Current
TRANSFORMER PRIMARY DESIGN					
PARAMETERS					
LP_TYP		_	990	uН	Typical Primary Inductance
LP_TOL		_	10	%	Primary inductance Tolerance
NP			67		Primary Winding Number of Turns
NB			8		Bias Winding Number of Turns
ALG			220	nH/T^2	Gapped Core Effective Inductance
ВМ			1771	Gauss	Maximum Flux Density at PO, VMIN (BM<3100)
BP			2584	Gauss	Peak Flux Density (BP<3700)
BAC			531	Gauss	AC Flux Density for Core Loss Curves (0.5 X Peak to Peak)
ur			1776		Relative Permeability of Ungapped Core
LG			0.26	mm	Gap Length (Lg > 0.1 mm)
BWE			31.2	mm	Effective Bobbin Width
OD			0.47	mm	Maximum Primary Wire Diameter including insulation
INS			0.06	mm	Estimated Total Insulation Thickness (= 2 * film thickness)
DIA			0.40	mm	Bare conductor diameter
AWG			27	AWG	Primary Wire Gauge (Rounded to next smaller standard AWG value)

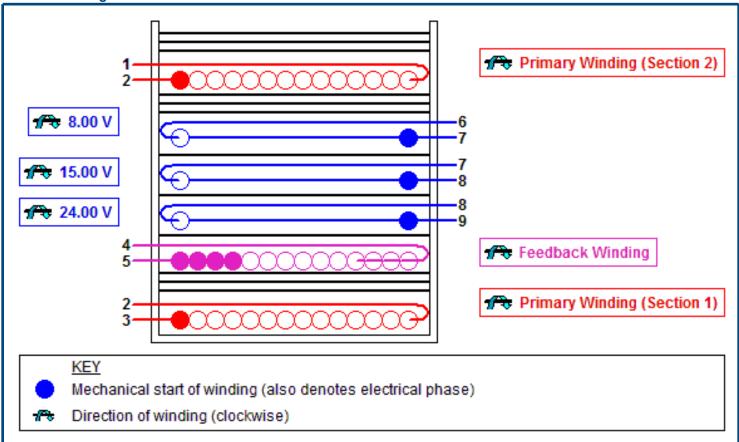
СМ			203	Cmils	Bare conductor effective area in circular mils
CMA		Warning	618	Cmils/Amp	!!! Info. This is an overdesign. You can decrease CMA (200 < CMA < 500) Decrease L(primary layers),increase NS,smaller Core
TRANSFORMER SECONDARY DESIGN PARAMETERS (SINGLE OUTPUT EQUIVALENT)					
Lumped parameters					
ISP			2.31	А	Peak Secondary Current
ISRMS			1.13	А	Secondary RMS Current
10			0.63	А	Power Supply Output Current
IRIPPLE			0.94	Α	Output Capacitor RMS Ripple Current
CMS			226	Cmils	Secondary Bare Conductor minimum circular mils
AWGS			26	AWG	Secondary Wire Gauge (Rounded up to next larger standard AWG value)
DIAS			0.41	mm	Secondary Minimum Bare Conductor Diameter
ODS			0.87	mm	Secondary Maximum Outside Diameter for Triple Insulated Wire
INSS			0.23	mm	Maximum Secondary Insulation Wall Thickness
VOLTAGE STRESS PARAMETERS					
VDRAIN			509	V	Peak voltage across drain to source of Linkswitch-HP
PIVS			105	V	Output Rectifier Maximum Peak Inverse Voltage
PIVB			46	V	Bias Rectifier Maximum Peak Inverse Voltage
TRANSFORMER SECONDARY DESIGN PARAMETERS (MULTIPLE OUTPUTS)					
1st output					
VO1	24.00		24.00	V	Output Voltage
101	0.25		0.25	Α	Output DC Current
PO1			6	W	Output Power
VD1			0.50	V	Output Diode Forward Voltage Drop
NS1			18.00		Output Winding Number of Turns
ISRMS1			0.453	Α	Output Winding RMS Current
IRIPPLE1			0.38	Α	Output Capacitor RMS Ripple Current
PIVS1			105	V	Output Rectifier Maximum Peak Inverse Voltage
CMS1			91	Cmils	Output Winding Bare Conductor minimum circular mils
AWGS1			30	AWG	Wire Gauge (Rounded up to next larger standard AWC value)
DIAS1			0.26	mm	Minimum Bare Conductor Diameter
ODS1			0.87	mm	Maximum Outside Diameter for Triple Insulated Wire
2nd output					
VO2	15.00		15.00	V	Output Voltage
102	0.50		0.50	A	Output DC Current
PO2	1		7.5	W	Output Power
VD2			0.70	V	Output Diode Forward Voltage Drop
	I	1	10.70	۱ ۳	Jacpar Diodo i ormana voltago Diop

ISRMS2		0.906	Α	Output Winding RMS Current
IRIPPLE2		0.76	Α	Output Capacitor RMS Ripple Current
PIVS2		69	V	Output Rectifier Maximum Peak Inverse Voltage
CMS2		181	Cmils	Output Winding Bare Conductor minimum circular mils
AWGS2		27	AWG	Wire Gauge (Rounded up to next larger standard AWG value)
DIAS2		0.36	mm	Minimum Bare Conductor Diameter
ODS2		1.30	mm	Maximum Outside Diameter for Triple Insulated Wire
3rd output				
VO3	8.00	8.00	V	Output Voltage
<i>I</i> O3	0.20	0.20	Α	Output DC Current
PO3		1.6	W	Output Power
VD3		0.70	V	Output Diode Forward Voltage Drop
NS3		7.00		Output Winding Number of Turns
ISRMS3		0.362	Α	Output Winding RMS Current
IRIPPLE3		0.30	Α	Output Capacitor RMS Ripple Current
PIVS3		39	V	Output Rectifier Maximum Peak Inverse Voltage
CMS3		72	Cmils	Output Winding Bare Conductor minimum circular mils
AWGS3		31	AWG	Wire Gauge (Rounded up to next larger standard AWG value)
DIAS3		0.23	mm	Minimum Bare Conductor Diameter
ODS3		2.23	mm	Maximum Outside Diameter for Triple Insulated Wire
Total power		15.1	W	!!! Warning: total output power not equal to PO (PO= 15 W)
Negative Output	N/A	N/A		If negative output exists enter Output number; e.g. If VO2 is negative output, select 2

Electrical Diagram



Mechanical Diagram



Winding Instruction

Primary Winding (Section 1)

Start on pin(s) 3 and wind 34 turns (x 1 filar) of item [5]. in 1 layer(s) from left to right. Winding direction is clockwise. On the final layer, spread the winding evenly across entire bobbin. Finish this winding on pin(s) 2.

Add 3 layers of tape, item [3], for insulation.

Feedback Winding

Start on any (temp) pin on the secondary side and wind 8 turns (x 4 filar) of item [5]. Winding direction is clockwise. Spread the winding evenly across entire bobbin. Finish this winding on pin(s) 4. Move end of wire from temp pin and terminate it on pin 5.

Add 1 layer of tape, item [3], for insulation.

Secondary Winding

Start on pin(s) 9 and wind 6 turns (x 1 filar) of item [6]. Spread the winding evenly across entire bobbin. Winding direction is clockwise. Finish this winding on pin(s) 8.

Add 1 layer of tape, item [3], for insulation.

Start on pin(s) 8 and wind 6 turns (x 1 filar) of item [7]. Spread the winding evenly across entire bobbin. Winding direction is clockwise. Finish this winding on pin(s) 7.

Add 1 layer of tape, item [3], for insulation.

Start on pin(s) 7 and wind 6 turns (x 1 filar) of item [8]. Spread the winding evenly across entire bobbin. Winding direction is clockwise. Finish this winding on pin(s) 6.

Add 3 layers of tape, item [3], for insulation.

Primary Winding (Section 2)

Start on pin(s) 2 and wind 33 turns (x 1 filar) of item [5]. in 1 layer(s) from left to right. Winding direction is clockwise. On the final layer, spread the winding evenly across entire bobbin. Finish this winding on pin(s) 1.

Add 3 layers of tape, item [3], for insulation.

Core Assembly

Assemble and secure core halves. Item [1].

Varnish

Dip varnish uniformly in item [4]. Do not vacuum impregnate.

Comments

- 1. Use of a grounded flux-band around the core may improve the EMI performance.
- 2. For non margin wound transformers use triple insulated wire for all secondary windings.

Materials

Item	Description
[1]	Core: EF25, , gapped for ALG of 220 nH/T²
[2]	Bobbin: Generic, 5 pri. + 4 sec.
[3]	Barrier Tape: Polyester film [1 mil (25 μm) base thickness], 15.60 mm wide
[4]	Varnish
[5]	Magnet Wire: 26 AWG (0.4 mm), Solderable Double Coated
[6]	Triple Insulated Wire: 30 AWG (0.25 mm)
[7]	Triple Insulated Wire: 25 AWG (0.45 mm)
[8]	Triple Insulated Wire: 24 AWG (0.55 mm)

Electrical Test Specifications

Parameter	Condition	Spec
Electrical Strength, VAC	60 Hz 1 second, from pins 1,2,3,4,5 to pins 6,7,8,9.	3000
Nominal Primary Inductance, μΗ	Measured at 1 V pk-pk, typical switching frequency, between pin 1 to pin 3, with all other Windings open.	990
Tolerance, ±%	Tolerance of Primary Inductance	10.0
Maximum Primary Leakage, μΗ	Measured between Pin 1 to Pin 3, with all other Windings shorted.	9.90

Although the design of the software considered safety guidelines, it is the user's responsibility to ensure that the user's power supply design meets all applicable safety requirements of user's product.

Transformer Construction Parameters

Var	Value	Units	Description
Core Type	EF25		Core Type
Bobbin Reference	Generic, 5 pri. + 4 sec.		Bobbin Reference
Bobbin Orientation	Horizontal		Bobbin type
Primary Pins	5		Number of Primary pins used
Secondary Pins	4		Number of Secondary pins used
LP	990	μН	Nominal Primary Inductance
ML	0.00	mm	Safety Margin on Left Width
MR	0.00	mm	Safety Margin on Right Width
LG	0.263	mm	Estimated Gap Length

Feedback Winding

Var	Value	Units	Description
NFB	8		Feedback Winding Number of Turns
Wire Size	26	AWG	Wire size of Feedback windings
Winding Type	Quadfilar (x4)		Wire type of Feedback windings
Layers	0.93		Feedback Winding Layers
Start Pin(s)	5		Starting pin(s) for Feedback winding
Termination Pin(s)	4		Termination pin(s) for Feedback winding

Primary Winding Section 1

Var	Value	Units	Description
NP1	34		Number of Primary Winding Turns in the First Section of Primary
Wire Size	26	AWG	Primary Winding - Wire Size
Winding Type	Single (x1)		Primary Winding - Number of Parallel Wire Strands
СМА	768.68	Cmils/A	Primary Winding Current Capacity. See Information section for detail
L	0.99		Primary Winding - Number of Layers
Start Pin(s)	3		Starting pin(s) for first section of primary winding
Termination Pin(s)	2		Termination pin(s) for first section of primary winding

Primary Winding Section 2

Var	Value	Units	Description
NP2	33		Rounded (Integer) Number of Primary winding turns in the second section of primary
Wire Size	26	AWG	Primary Winding - Wire Size
Winding Type	Single (x1)		Primary Winding - Number of Parallel Wire Strands
L2	0.96		Primary Number of Layers in 2nd split winding
Start Pin(s)	2		Starting pin(s) for the second section of primary winding
Termination Pin(s)	1		Termination pin(s) for the second section of primary winding

Output 1

Var	Value	Units	Description
			2000

VO	24.00	V	Typical Output Voltage
10	0.25	Α	Output Current
VOUT_ACTUAL	24.00	V	Actual Output Voltage
NS	6		Secondary Number of Turns
Wire Size	30	AWG	Wire size of secondary winding
Winding Type	Single (x1)		Output winding number of parallel strands
ISRMS_WINDING	0.453	Α	Secondary Winding RMS Current
CMAS	221	Cmils/A	Secondary Winding Current Capacity
L_S_OUT	0.17		Secondary Output Winding Layers
Start Pin(s)	9		Starting pin(s) for Output winding
Termination Pin(s)	8		Termination pin(s) for Output winding

Output 2

Var	Value	Units	Description	
VO	15.00	V	Typical Output Voltage	
10	0.50	A	Output Current	
VOUT_ACTUAL	15.63	V	Actual Output Voltage	
NS			Secondary Number of Turns	
Wire Size	25	AWG	Wire size of secondary winding	
Winding Type	Single (x1)		Output winding number of parallel strands	
ISRMS_WINDING	1.359	А	Secondary Winding RMS Current	
CMAS	236	Cmils/A	Secondary Winding Current Capacity	
L_S_OUT	0.25		Secondary Output Winding Layers	
Start Pin(s)	8		Starting pin(s) for Output winding Termination pin(s) for Output winding	
Termination Pin(s)	7			

Output 3

Var	Value	Units	Description	
VO	8.00	V	Typical Output Voltage	
10	0.20	A	Output Current	
VOUT_ACTUAL	7.47	V	Actual Output Voltage	
NS	6		Secondary Number of Turns	
Wire Size	24	AWG	Wire size of secondary winding	
Winding Type	Single (x1)		Output winding number of parallel strands	
ISRMS_WINDING	1.721	A	Secondary Winding RMS Current	
CMAS	235	Cmils/A	Secondary Winding Current Capacity	
L_S_OUT	0.29		Secondary Output Winding Layers	
Start Pin(s)	7		Starting pin(s) for Output winding	
Termination Pin(s)	6		Termination pin(s) for Output winding	

		Description	Fix	Ref. #
			Choose smaller core size, decrease layers (L), VOR, increase secondary turns (NS), KP.	219